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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR		AT AT	TORNEY DOCKET NO
09/546,174	04/11/00	LIU		С,	JIA 462C1
023995 RABIN & CHAMPAGNE, PC		IM52/0403		EXAMINER	
				SERGENT,R	
1101 14TH STREET, NW				ART UNIT	PAPER NUMBER
SUITE 500 WASHINGTON DC 20005				1711	2
				DATE MAILED:	
					04/03/01

Please find below and/or attached an Office communication concerning this application or proceeding.

**Commissioner of Patents and Trademarks** 

Application No. 09/546,174 Applicant(s)

Liu et al.

## Office Action Summary

Examiner

Group Art Unit Rabon Sergent

1711

☐ Responsive to communication(s) filed on	·
☐ This action is <b>FINAL</b> .	
☐ Since this application is in condition for allowance of in accordance with the practice under Ex parte Que	except for formal matters, prosecution as to the merits is closed ayle, 1935 C.D. 11; 453 O.G. 213.
is longer, from the mailing date of this communication	on is set to expire <u>three</u> month(s), or thirty days, whichever it. Failure to respond within the period for response will cause the Extensions of time may be obtained under the provisions of
Disposition of Claims	
	is/are pending in the application.
Of the above, claim(s)	is/are withdrawn from consideration.
Claim(s)	
☐ Claim(s)	is/are objected to.
	are subject to restriction or election requirement.
Application Papers  See the attached Notice of Draftsperson's Pater The drawing(s) filed on	are objected to by the Examiner.  is approved disapproved.  is approved.  is approved.
Attachment(s)  X Notice of References Cited, PTO-892  X Information Disclosure Statement(s), PTO-1449,  Interview Summary, PTO-413  Notice of Draftsperson's Patent Drawing Review  Notice of Informal Patent Application, PTO-152	v, PTO-948
SEE OFFICE ACT	TION ON THE FOLLOWING PAGES

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## **DETAILED ACTION**

1. Applicant has not complied with one or more conditions for receiving the benefit of an earlier filing date under 35 U.S.C. 120 as follows:

An application in which the benefits of an earlier application are desired must contain a specific reference to the prior application(s) in the first sentence of the specification (37 CFR 1.78).

2. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

3. Claims 1-20 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-21 of U.S. Patent No. 6,117,345. Although the conflicting claims are not identical, they are not patentably distinct from each other because the subject matter of the instant set of claims is an obvious variant of the patented claims. With respect to claims 1-19, though the claims are silent regarding a masking layer, such a layer is disclosed and the instant claims are open to the inclusion of such a layer.

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Furthermore, the use of a masking layer is considered to constitute an obvious process design choice, with respect to the etching art.

4. Claim 8 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Within line 2 of claim 8, "antireflection" should be "antireflective".

5. Claim 2 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

It is unclear how the use of "primarily" is intended to further limit the claim.

6. Claims 1-8 and 20 are rejected under 35 U.S.C. 112, first paragraph, because the specification, while being enabling for methods wherein the gaps are filled with dielectric material by the step of high density plasma chemical vapor deposition, does not reasonably provide enablement for methods wherein the deposition step fails to fill the gaps. The specification does not enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to use the invention commensurate in scope with these claims.

The deposition steps of claims 1 and 20 do not specifically require that the dielectric material fill the gaps; however, this is a central objective of applicants' application.

7. Claims 1, 2, and 5-8 are rejected under 35 U-S.C. 112, first paragraph, because the specification, while being enabling for methods wherein high density plasma chemical vapor

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deposition is used to deposit the dielectric material within the gaps between the wiring lines, does not reasonably provide enablement for methods utilizing other deposition techniques to deposit the dielectric material. The specification does not enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to use the invention commensurate in scope with these claims.

Applicants have provided adequate enablement only for processes utilizing high density plasma chemical vapor deposition, and the position is taken that the claims should be limited in accordance with the teachings of the specification.

8. Claims 1-19 are rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to enable one skilled in the art to which it pertains, or with which it is most nearly connected, to make and/or use the invention.

It is unclear how the antireflective coatings (claim 1) and cap layer (claim 9) and layers directly beneath them are selectively etched. Applicants' claims fail to recite a mask or photoresist layer.

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Any inquiry concerning this communication should be directed to R. Sergent at telephone number (703) 308-2982.

Sergent/sp/om March 7, 2001 March 21, 2001

RABON SERGENT PRIMARY EXAMINER